SCOPE: CMOS, BUFFERED, MULTIPLYING 8-BIT D/A CONVERTER

Device Type	Generic Number	Circuit Function
01	MX7528S(x)/883B	DAC with ±4 LSB
02	MX7528T(x)/883B	DAC with ±2 LSB
03	MX7528U(x)/883B	DAC with ±1 LSB

Case Outline(s). The case outlines shall be designated in Mil-Std-1835 and as follows:

Outline Letter	Mil-Std-1835	Case Outline	Package Code
Q	GDIP1-T20 or CDIP2-T20	20 LEAD CERDIP	J20

Absolute Maximum Ratings:

V_{DD} to AGND ..... 0V, + 17V
V_{DD} to DGND ..... 0V, + 17V
V_{RFBA}, V_{RFBB} to DGND ..... ±25V
V_{REFA}, V_{REFB} to AGND ..... ±25V
Digital Input Voltage to DGND ..... -0.3V to V_{DD}+0.3V
V pin 1 to DGND ..... -0.3V to V_{DD}
V pin 2, V pin 20 to AGND ..... -0.3V to V_{DD}+0.3V
AGND to DGND ..... -0.3V, V_{DD}+0.3V
DGND to AGND ..... +0.3V
Lead Temperature (soldering, 10 seconds) ..... +300°C
Storage Temperature ..... -65°C to +150°C

Continuous Power Dissipation ..... T_A=+70°C
20 pin CERDIP(derate 11.1mW/°C above +70°C) 889mW

Junction Temperature T_J ..... +150°C
Thermal Resistance, Junction to Case, ΘJC
20 pin CERDIP..... 40°C/W
Thermal Resistance, Junction to Ambient, ΘJA:
16 pin CERDIP..... 90°C/W

Recommended Operating Conditions

Ambient Operating Range (T_A) ..... -55°C to +125°C
Supply Voltage Range (V_{DD}) .....+4.75V to +5.25V and +14.25V to +15.75V
V_{REF} DAC A=V_{REF} DAC B ..... +10V
OUT DAC A=OUT DAC B 0V

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TABLE 1. ELECTRICAL TESTS:

TEST	Symbol	CONDITIONS -55 °C <=T_A<= +125°C 1/ Unless otherwise specified	Group A Subgroup	Device type	Limits Min	Limits Max	Units
ACCURACY							
Resolution NOTE 4	RES	V_{DD}=+5V and V_{DD}=+15V	1,2,3	All	8.0		Bits
Relative Accuracy	RA	V_{DD}=+5V and V_{DD}=+15V	1,2,3	01		±1.0	LSB
Relative Accuracy	RA	V_{DD}=+5V and V_{DD}=+15V	1,2,3	02,03		±0.5	LSB
Differential Nonlinearity	DNL	V_{DD}=+5V and V_{DD}=+15V Monotonic to 8-Bits	1,2,3	All	-1	1	LSB
Gain Error NOTE 2	AE	V_{DD}=+5V and V_{DD}=+15V DAC register loaded with 1111 1111 1111	1	01 02 03		±4.0 ±2.0 ±1.0	LSB
Gain Error NOTE 2	AE	V_{DD}=+5V V_{DD}=+15V	2,3	01		±6.0 ±5.0	LSB
Gain Error NOTE 2	AE	V_{DD}=+5V V_{DD}=+15V	2,3	02		±4.0 ±3.0	LSB
Gain Error NOTE 2	AE	V_{DD}=+5V V_{DD}=+15V	2,3	03		±3.0 ±1.0	LSB
Power Supply Rejection	PSRR	V_{DD}=+5V, ΔV_{DD}=±5%	1 2,3	All		±0.02 ±0.04	%/%
Power Supply Rejection	PSRR	V_{DD}=+15V, ΔV_{DD}=±5%	1 2,3	All		±0.01 ±0.02	%/%
Output Leakage Current OUTA, OUTB	I_{OL}	V_{DD}=+5V, DAC latches loaded with 0000 0000	1 2,3	All		±50 ±400	nA
Output Leakage Current OUTA, OUTB	I_{OL}	V_{DD}=+15V, DAC latches loaded with 0000 0000	1 2,3	All		±50 ±200	nA
Reference Input Resistance VREFA, VREFB	R_{IN}	V_{DD}=+5V and +15V	4,5,6	All	8	15	kΩ
Digital Input High Voltage	V_{IH}	V_{DD}=+5V V_{DD}=+15V	1,2,3	All	2.4 13.5		V
Digital Input Low Voltage	V_{IL}	V_{DD}=+5V V_{DD}=+15V	1,2,3	All		0.8 1.5	V
Digital Input Leakage Current	I_{IN}	V_{DD}=+5V V_{IN}=0V or V_{DD}	1 2,3	All		±1.0 ±10	µA
Digital Input Leakage Current	I_{IN}	V_{DD}=+15V V_{IN}=0V or V_{DD}	1 2,3	All		±1.0 ±10	µA
Supply Current	I_{DD}	V_{DD}=+5V All digital inputs V_{DD}=+15V V_{IL} or V_{IH}	1,2,3	All		2.0 2.0	mA
Supply Current	I_{DD}	V_{DD}=+5V & +15V. All digital inputs 0V or V_{DD}	1 2,3	All		100 500	µA
Gain Temperature Coefficient NOTE 3	TC_{AE}	V_{DD}=+5V V_{DD}=+15V	1,2,3	All		±70 ±35	ppm/°C
Feedthrough Error V_{REF}A to OUTA and V_{REF}B to OUTB	$FT_{REF}A$	V_{DD}=+5V or V_{DD}=+15V, V_{REF}=+10V, 100kHz sinewave, DAC latches loaded with 0000 0000 NOTE 3, NOTE 5	4,5,6	All		-55	dB

TEST	Symbol	CONDITIONS -55 °C <=T_A<= +125°C 1/ Unless otherwise specified	Group A Subgroup	Device type	Limits Min	Limits Max	Units
Digital Input Capacitance NOTE 3, 6	C_{IN}	V_{DD}=+5V and V_{DD}=+15V, DB0-DB7	4	All		10	pF
Digital Input Capacitance NOTE 3, 6	C_{IN}	V_{DD}=+5V & V_{DD}=+15V WR, CS, DACA/DACB	4	All		15	pF
ANALOG INPUTS							
Digital Output pin 2 Capacitance 3/ pin 20	C_{OUTA} C_{OUTB}	V_{DD}=+5V and 15V, DAC latches loaded with 0000 0000	4	All		50 50	pF
Digital Output pin 2 Capacitance 3/ pin 20	C_{OUTA} C_{OUTB}	V_{DD}=+5V and 15V, DAC latches loaded with 1111 1111	4	All		120 120	pF
TIMING							
Chip select to write setup time NOTE 3, 7	t_{CS}	V_{DD}=+5V V_{DD}=+15V	9,10,11	All	250 180		ns
Chip select to write hold time NOTE 3, 7	t_{CH}	V_{DD}=+5V V_{DD}=+15V	9,10,11	All	20 10		ns
Write pulse width NOTE 3, 7	t_{WR}	V_{DD}=+5V, $t_{CS}\geq t_{WR}$, $t_{CH}\geq 0$ V_{DD}=+15V, $t_{CS}\geq t_{WR}$, $t_{CH}\geq 0$	9,10,11	All	220 180		ns
Data valid to write setup time NOTE 3, 7	t_{DS}	V_{DD}=+5V V_{DD}=+15V	9,10,11	All	220 180		ns
Data valid to write hold time NOTE 3, 7	t_{DH}	V_{DD}=+5V V_{DD}=+15V	9,10,11	All	10 10		ns
Data select to write setup time NOTE 3,7	t_{AS}	V_{DD}=+5V V_{DD}=+15V	9,10,11	All	250 180		ns
Data select to write hold time NOTE 7	t_{AH}	V_{DD}=+5V V_{DD}=+15V	9,10,11	All	20 10		ns
Reference input resistance match	$\frac{RMIN}{\Delta V_{REF}}$	V_{DD}=+5V V_{DD}=+15V	4,5,6	All		±1 ±1	%
Channel to Channel isolation NOTE 3 V_{REF}A to OUTB	CHISO	V_{DD}=+5V or +15V. V_{REF}A=±10V, 100kHz sinewave, V_{REF}B=0V	4,5,6	All		-60	dB
Channel to Channel isolation NOTE 3 V_{REF}B to OUTA	CHISO	V_{DD}=+5V or +15V. V_{REF}B=±10V, 100kHz sinewave, DAC, V_{REF}A=0V	4,5,6	All		-60	dB
Output Current Settling Time NOTE 3, NOTE 8	t_{SL}	V_{DD}=+5V V_{DD}=+15V	9,10,11	All		600 350	ns

NOTE 1: V_{OUT}1=0V; VREF=+10V, AGND=DGND unless otherwise specified.
NOTE 2: Measured using internal RFBA and RFBB. Gain error is adjustable.
NOTE 3: Characteristics supplied for use as a typical design limit, but not production tested.

NOTE 4: Guaranteed, if not tested.
NOTE 5: Feedthrough error can be reduced by connecting the metal lid to ground.
NOTE 6: Subgroup 4 (C_{IN} and C_{OUT} measurements) shall be measured only for the inital test and after process or design changes which may affect capacitance.
NOTE 7: Timing in accordance with Write Cycle Timing Diagram in Commercial Data Sheet.
NOTE 8: To 0.5LSB, OUTA/OUTB=100Ω in parallel with 13pF. $\overline{CS}$ $\overline{WR}$
DB0-DB7=0V to V_{DD} or V_{DD} to 0V, WR=CS=0V

MODE SELECTION TABLE:

$\overline{CS}$	$\overline{WR}$	$\overline{DACA/DACB}$	DACA	DACB
L	L	L	Write	Hold
L	L	H	Hold	Write
H	X	X	Hold	Hold
X	H	X	Hold	Hold

L = Low state, H = High state, X = Don't care

ORDERING INFORMATION:

	Package	**Pkg. Code**	
01	20 pin CERDIP	J20	MX7528SQ/883B
02	20 pin CERDIP	J20	MX7528TQ/883B
03	20 pin CERDIP	J20	MX7528UQ/883B

TERMINAL CONNECTIONS:

	J20
Pin	
1	AGND
2	OUTA
3	RFBA
4	VREFA
5	DGND
6	$\overline{DACA/DACB}$
7	(MSB)DB7
8	DB6
9	DB5
10	DB4
11	DB3
12	DB2
13	DB1
14	DB0(LSB)
15	$\overline{CS}$
16	$\overline{WR}$
17	V_{DD}
18	VREFB
19	RFBB
20	OUTB

QUALITY ASSURANCE

Sampling and inspection procedures shall be in accordance with MIL-Prf-38535, Appendix A as specified in Mil-Std-883.

Screening shall be in accordance with Method 5004 of Mil-Std-883. Burn-in test Method 1015:

1. Test Condition, A, B, C, or D.
2. TA = +125°C minimum.
3. Interim and final electrical test requirements shall be specified in Table 2.

Quality conformance inspection shall be in accordance with Method 5005 of Mil-Std-883, including Groups A, B, C, and D inspection.

Group A inspection:

1. Tests as specified in Table 2.
2. Selected subgroups in Table 1, Method 5005 of Mil-Std-883 shall be omitted.

Group C and D inspections:

a. End-point electrical parameters shall be specified in Table 1.
b. Steady-state life test, Method 1005 of Mil-Std-883:
   1. Test condition A, B, C, D.
   2. TA = +125°C, minimum.
   3. Test duration, 1000 hours, except as permitted by Method 1005 of Mil-Std-883.

TABLE 2. ELECTRICAL TEST REQUIREMENTS

Mil-Std-883 Test Requirements	Subgroups per Method 5005, Table 1
Interim Electric Parameters Method 5004	1
Final Electrical Parameters Method 5005	1*, 2, 3
Group A Test Requirements Method 5005	1, 2, 3, 4, 5, 6, 9**, 10**, 11**
Group C and D End-Point Electrical Parameters Method 5005	1

* PDA applies to Subgroup 1 only.

** Subgroups 9, 10 and 11, if not tested shall be guaranteed to the limits specified in Table 1.

LifeElectronics
Живое партнерство

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ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

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Тел: +7 (812) 336 43 04 (многоканальный)
Email: org@lifeelectronics.ru

www.lifeelectronics.ru